



# M T B F

(EIAJ RCR-9102)

Model TUXS200F50

No.	P a r t s		Q'ty of Device	Failure rate [10 <sup>-6</sup> /H]	Reference
1	I C	Monolithic	17	0.5650	
2		Hybrid	0	0.0000	
3	Transistors		14	0.7986	
4	Diodes		33	0.5580	
5	LED·Optocouplers		2	0.1400	
6	Resistors		130	0.6702	
7	Capacitors		95	0.7030	
8	Transformer·Choke Coil		4	0.0920	
9	Connectors		766	0.2374	
10	Others		2	0.1130	
Total Failure Rate [10 <sup>-6</sup> /H]				3.8772	

M T B F	[H]	258,000
Ambient Temperature	[℃]	—
Load Factor	[%]	—